MOC215

[CTR = 20% Min]

Small Outline Optoisolators Transistor Output (Low Input Current)

These devices consist of a gallium arsenide infrared emitting diode optically coupled to a monolithic silicon phototransistor detector, in a surface mountable, small outline, plastic package. They are ideally suited for high density applications, and eliminate the need for through-the-board mounting.

- Convenient Plastic SOIC-8 Surface Mountable Package Style
- Low LED Input Current Required, for Easier Logic Interfacing
- Standard SOIC-8 Footprint, with 0.050" Lead Spacing
- Shipped in Tape and Reel, which Conforms to EIA Standard RS481A
- Compatible with Dual Wave, Vapor Phase and IR Reflow Soldering
- High Input–Output Isolation of 3000 Vac (rms) Guaranteed
- UL Recognized 🔊 File #E54915

Ordering Information:

- To obtain MOC215, 216, 217 in Tape and Reel, add R2 suffix to device numbers: R2 = 2500 units on 13" reel
- To obtain MOC215, 216, 217 in quantities of 50 (shipped in sleeves) No Suffix

Marking Information:

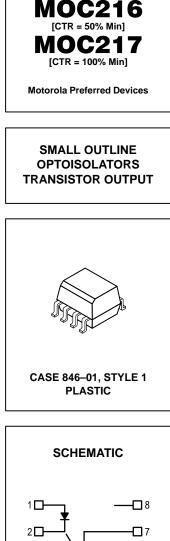
- MOC215 = 215
- MOC216 = 216
- MOC217 = 217

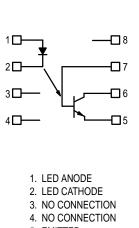
Applications:

- Low power Logic Circuits
- · Interfacing and coupling systems of different potentials and impedances
- Telecommunications equipment
- Portable electronics

MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
INPUT LED			
Forward Current — Continuous	١ _F	60	mA
Forward Current — Peak (PW = 100 µs, 120 pps)	I _F (pk)	1.0	А
Reverse Voltage	٧ _R	6.0	V
LED Power Dissipation @ T _A = 25°C Derate above 25°C	PD	90 0.8	m₩ m₩/°C
OUTPUT TRANSISTOR			
Collector–Emitter Voltage	VCEO	30	V
Collector-Base Voltage	VCBO	70	V
Emitter–Collector Voltage	V _{ECO}	7.0	V
Collector Current — Continuous	IC	150	mA
Detector Power Dissipation @ T _A = 25°C Derate above 25°C	PD	150 1.76	mW mW/°C





- 5. EMITTER
- 6. COLLECTOR
- 7. BASE
- 8. NO CONNECTION

IOTOROLA

NOTE: Thickness through insulation between input and output is ≥ 0.5 mm.

Preferred devices are Motorola recommended choices for future use and best overall value.

REV 1

MOC215 MOC216 MOC217

MAXIMUM RATINGS — continued (T_A = 25°C unless otherwise noted)

Rating		Symbol	Val	Value		
OTAL DEVICE						
Input–Output Isolation Voltage(1,2) (60 Hz, 1.0 sec. duration)		VISO	30	3000		
Total Device Power Dissipation @ T _A = 25°C Derate above 25°C			PD	250 2.94		mW mW/°C
Ambient Operating Temperature Range ⁽³⁾			TA	T _A -55 to +100		°C
Storage Temperature Range ⁽³⁾			T _{stg}	-55 to +150		°C
Lead Soldering Temperature (1/16" from case, 10 sec. duration)			_	26	260	
ELECTRICAL CHARACTERISTICS (T _A = 25	°C unless otherwise	e noted) ⁽⁴⁾				
Characteristic		Symbol	Min	Typ ⁽⁴⁾	Max	Unit
NPUT LED		•				
Forward Voltage ($I_F = 1.0 \text{ mA}$)		VF	—	1.05	1.3	V
Reverse Leakage Current (V _R = 6.0 V)		IR	-	0.1	100	μΑ
Capacitance		С	—	18	_	pF
OUTPUT TRANSISTOR			-			_
Collector–Emitter Dark Current $(V_{CE} = 5.0)$	V, T _A = 25°C)	ICEO1	—	1.0	50	nA
(V _{CE} = 5.0	V, T _A = 100°C)	ICEO2	—	1.0	_	μΑ
Collector–Emitter Breakdown Voltage (I _C = 100 μ A)		V(BR)CEO	30	90		V
Emitter–Collector Breakdown Voltage (I _E = 100 μ A)		V(BR)ECO	7.0	7.8		V
Collector–Emitter Capacitance (f = 1.0 MHz, $V_{CE} = 0$)		CCE	—	7.0		pF
COUPLED						
Output Collector Current (IF = 1.0 mA, V_{CE} = 5.0 V)	MOC215 MOC216 MOC217	I _C (CTR) ⁽⁵⁾	200 (20) 500 (50) 1.0 (100)	500(50) 800 (80) 1.3 (130)		μΑ (%) μΑ (%) mA (%)
Collector–Emitter Saturation Voltage (I _C = 100 μ /	A, I _F = 1.0 mA)	V _{CE(sat)}	—	0.35	0.4	V
Turn–On Time (I _C = 2.0 mA, V _{CC} = 10 V, R _L = 100 Ω)		ton	—	7.5	_	μs
Turn–Off Time (I _C = 2.0 mA, V _{CC} = 10 V, R _L = 100 Ω)		^t off	—	5.7	_	μs
Rise Time (I _C = 2.0 mA, V _{CC} = 10 V, R _L = 100 Ω)		tr	—	3.2	_	μs
Fall Time (I _C = 2.0 mA, V _{CC} = 10 V, R _L = 100 Ω)		t _f	—	4.7	_	μs
Input–Output Isolation Voltage (f = 60 Hz, t = 1.0 sec.) ^(1,2)		VISO	3000	_		Vac(rms)
Isolation Resistance $(V_{I-O} = 500 \text{ V})^{(2)}$		RISO	10 ¹¹	_		Ω
Isolation Capacitance $(V_{I-O} = 0, f = 1.0 \text{ MHz})^{(2)}$		CISO	_	0.2	_	pF

1. Input–Output Isolation Voltage, V_{ISO} , is an internal device dielectric breakdown rating. 2. For this test, pins 1 and 2 are common, and pins 5, 6 and 7 are common.

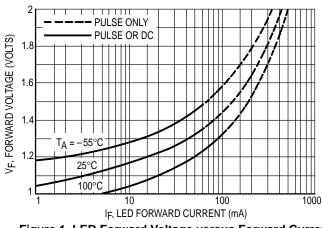
3. Refer to Quality and Reliability Section in Opto Data Book for information on test conditions.

4. Always design to the specified minimum/maximum electrical limits (where applicable).

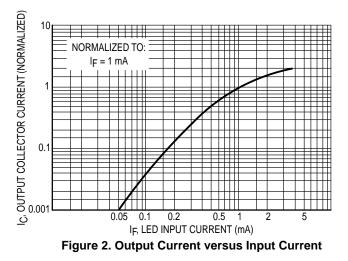
5. Current Transfer Ratio (CTR) = $I_C/I_F \times 100\%$.

MOC215 MOC216 MOC217

TYPICAL CHARACTERISTICS







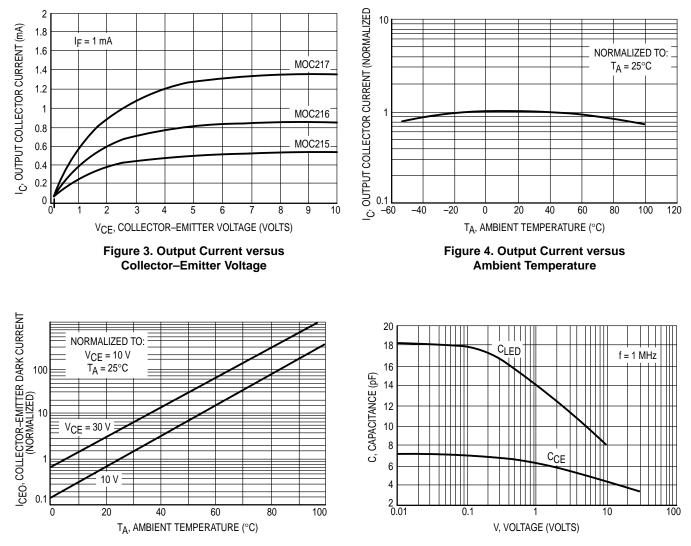
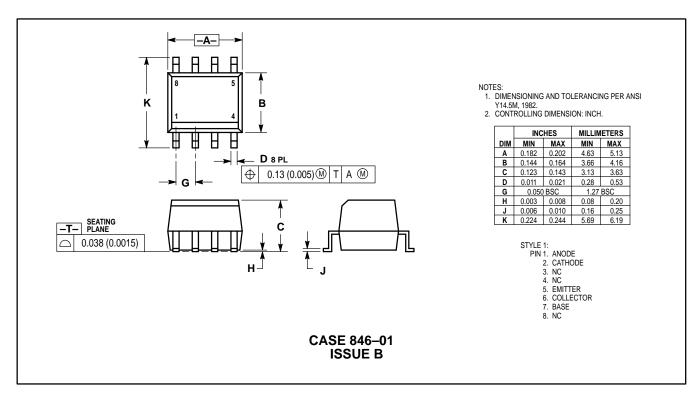


Figure 5. Dark Current versus Ambient Temperature

Figure 6. Capacitance versus Voltage

MOC215 MOC216 MOC217

PACKAGE DIMENSIONS



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